

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, weni four in any manner.



FQB9N50C

N-Channel QFET[®] MOSFET 500 V, 9 A, 800 m Ω

Features

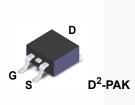
- + 9 A, 500 V, $R_{DS(on)}$ = 800 m $\Omega\,$ (Max.) @ V_{GS} = 10 V, I_D = 4.5 A
- Low Gate Charge (Typ. 28 nC)
- Low Crss (Typ. 24 pF)
- 100% Avalanche Tested

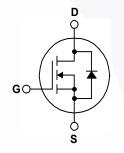
November 2013

FQB9N50C — N-Channel QFET[®] MOSFET

Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQB9N50CTM	Unit
V _{DSS}	Drain-Source Voltage		500	V
I _D	Drain Current - Continuous ($T_c = 25^{\circ}C$)		9	А
	- Continuous (T _C = 100°C)		5.4	А
I _{DM}	Drain Current - Pulsed	(Note 1)	36	A
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		360	mJ
I _{AR}	Avalanche Current	(Note 1)	9	A
E _{AR}	Repetitive Avalanche Energy (No		13.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
P _D	Power Dissipation ($T_C = 25^{\circ}C$)		135	W
	- Derate above 25°C		1.07	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes,		300	°C
'L	1/8" from case for 5 seconds		500	

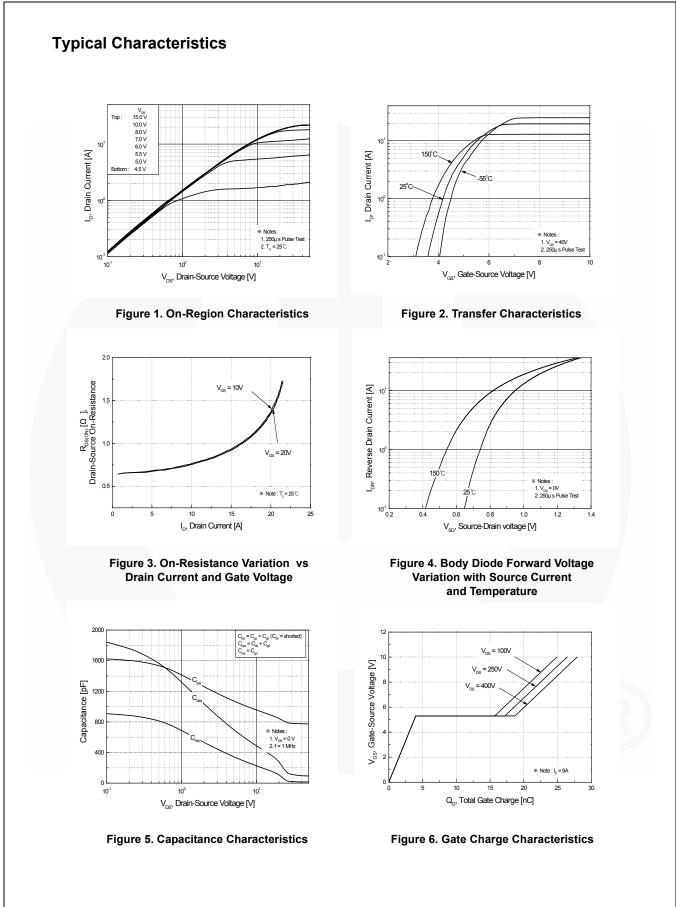
Thermal Characteristics

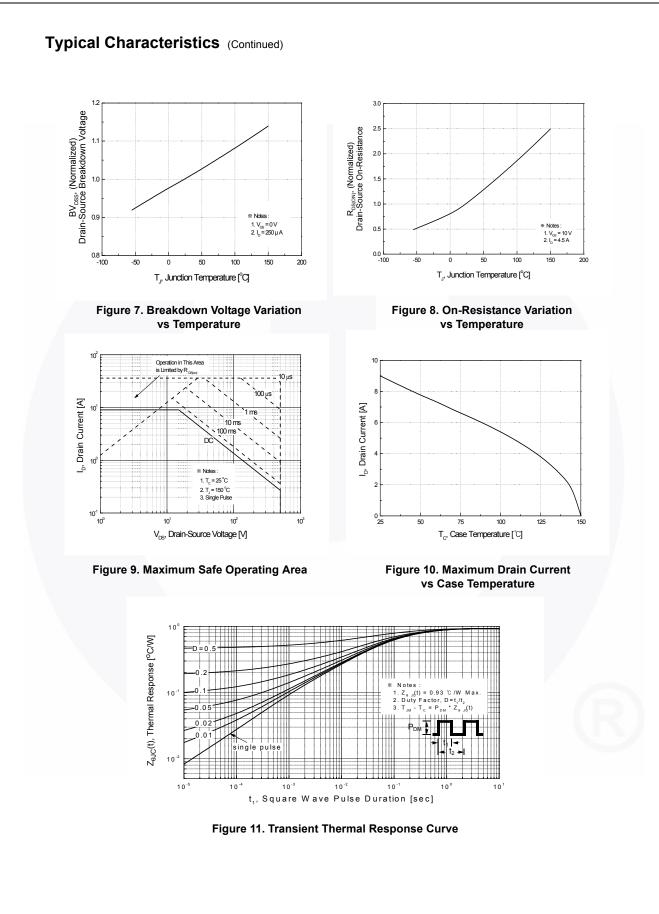
Symbol	Parameter	FQB9N50CTM	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.93	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	C/W	

1

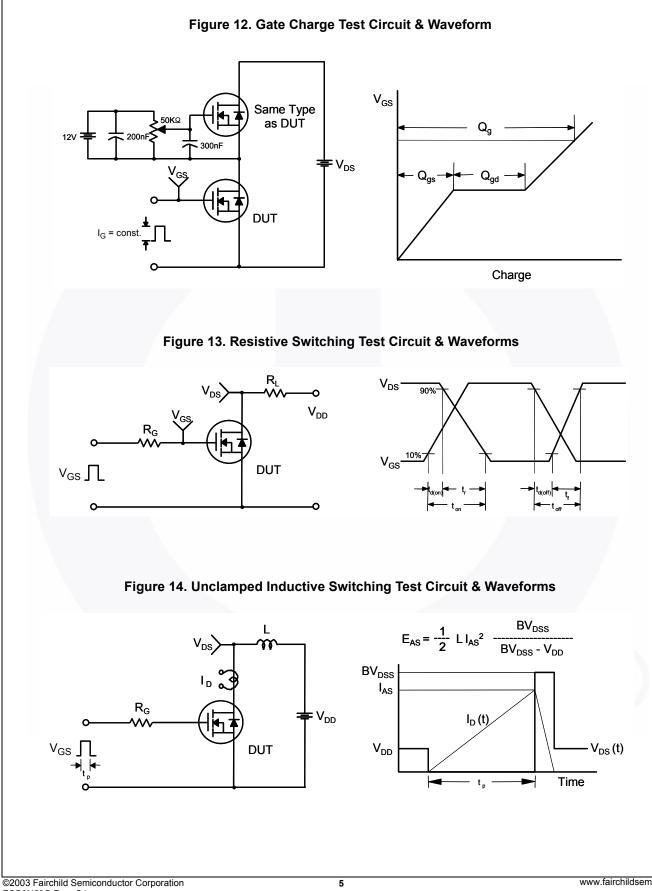
Device MarkingDeviceFQB9N50CFQB9N50CTM		Package Reel Size		Таре	Tape Width		Quantity	
		D ² -PAK	330 mm	24	24 mm		800 units	
ectri	cal Chara	acteristics T _C = 25°C	c unless otherwise	noted.				
Symbol		Parameter	Test C	Conditions	Min	Тур	Max	Unit
	rootorioti							
BV _{DSS}	Drain-Source Breakdown Voltage		V _{GS} = 0 V, I _D = 250 μA		500			V
ΔBV _{DSS}			V _{GS} = 0 V, I _D = 250 μA		500			v
ΔDV_{DSS}	Coefficient	Voltage Temperature	I_D = 250 µA, Referenced to 25°C			0.57		V/°C
I _{DSS}	Zero Gate Voltage Drain Current		V_{DS} = 500 V, V_{GS} = 0 V				1	μA
022			V_{DS} = 400 V, T_{C} = 125°C				10	μA
GSSF	-	Leakage Current, Forward	V_{GS} = 30 V, V_{DS}				100	nA
GSSR	Gate-Body	Leakage Current, Reverse	V_{GS} = -30 V, V_{DS}	_S = 0 V			-100	nA
On Cha	racteristic	s						
V _{GS(th)}	Gate Thres	hold Voltage	$V_{DS} = V_{GS}, I_D =$	250 μΑ	2.0		4.0	V
R _{DS(on)}	Static Drain On-Resista		V _{GS} = 10 V, I _D =	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		0.65	0.8	Ω
FS		ansconductance	V _{DS} = 40 V, I _D =	4.5 A		6.5		S
Dynam C _{iss} C _{oss} C _{rss}	ic Charact Input Capac Output Cap Reverse Tra	citance	V _{DS} = 25 V, V _{GS} f = 1.0 MHz	= 0 V,		790 130 24	1030 170 30	pF pF
	ng Charao			_		10	45	
d(on)	Turn-On De Turn-On Ris	,	V _{DD} = 250 V, I _D = 9 A,			18	45 140	ns
r	Turn-Off De		$R_{G} = 25 \Omega$	R _G = 25 Ω (Note 4)		65 93	140	ns
d(off) f	Turn-Off Fa		-			93 64	195	ns
τ 2 _g	Total Gate 0			- 0 4		28	35	ns nC
∡g ⊋ _{gs}	Gate-Sourc	, and the second	V_{DS} = 400 V, I _D = 9 A, V_{GS} = 10 V (Note 4)			4		nC
∽gs ⊋ _{gd}	Gate-Drain	-				15		nC
				· · · ·				
s		de Characteristics ar Continuous Drain-Source Dic		•			9	A
SM		Pulsed Drain-Source Diode Forward Current				36	A	
/ _{SD}		ce Diode Forward Voltage	$V_{GS} = 0 V, I_S = 9 A$				1.4	V
rr		ecovery Time	$V_{GS} = 0 V, I_S = 9 A,$			335		ns
		covery Charge	$dI_{\rm F}$ / $dt = 100 {\rm A/\mu}$			2.95		μC
Q _{rr}	Reverse RE							

FQB9N50C — N-Channel QFET[®] MOSFET





FQB9N50C — N-Channel QFET[®] MOSFET



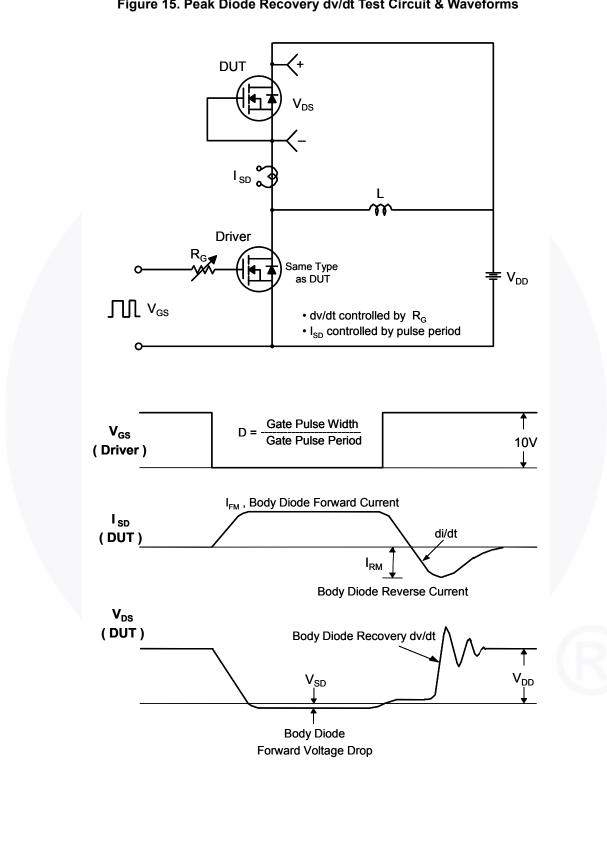


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

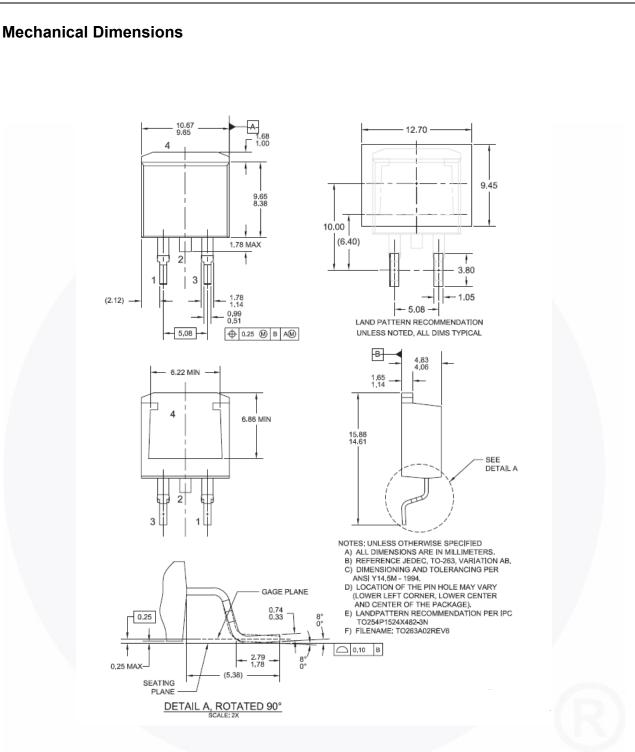


Figure 16. TO263 (D²PAK), Molded, 2-Lead, Surface Mount

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT263-002

FQB9N50C — N-Channel QFET[®] MOSFET



SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AccuPower™	F-PFS™_	-45	Sync-Lock™
AX-CAP [®] *	FRFET®	®	SYSTEM ®*
BitSiC™	Global Power Resource SM	PowerTrench [®]	GENERAL
Build it Now™	GreenBridge™	PowerXS™	TinyBoost [®]
CorePLUS™	Green FPS™	Programmable Active Droop™	TinyBuck [®]
CorePOWER™	Green FPS™ e-Series™	QFET®	TinyCalc™
CROSSVOLT™	Gmax™	QS™	TinyLogic®
CTL™	GTO™	Quiet Series™	TINYOPTO™
Current Transfer Logic™	IntelliMAX™	RapidConfigure™	TinyPower™
DEUXPEED®	ISOPLANAR™		TinyPWM™
Dual Cool™	Marking Small Speakers Sound Louder		TinyWire™
EcoSPARK [®]	and Better™	Saving our world, 1mW/W/kW at a time™	TranSiC™
EfficentMax™	MegaBuck™	SignalWise™	TriFault Detect™
ESBC™	MICROCOUPLER™	SmartMax™	TRUECURRENT®*
F R	MicroFET™	SMART START™	μSerDes™
+	MicroPak™	Solutions for Your Success™	
Fairchild [®]	MicroPak2™	SPM®	SerDes
Fairchild Semiconductor [®]	MillerDrive™	STEALTH™	UHC [®]
FACT Quiet Series™	MotionMax™	SuperFET®	Ultra FRFET™
FACT®	mWSaver®	SuperSOT™-3	UniFET™
FAST [®]	OptoHiT™	SuperSOT™-6	
FastvCore™	OPTOLOGIC®	SuperSOT [™] -8	VCX™
FETBench™	OPTOPLANAR®	SupreMOS®	VisualMax™
FPS™		SyncFET™	VoltagePlus™
			XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: <u>FQB9N50CTM</u>